

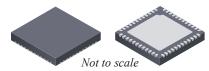
Automotive MCU with 90 V MOSFET Driver

FEATURES AND BENEFITS

- 5.5 to 90 V supply voltage operating range
- 32-bit ARM cortex M4 CPU core
 - □ Up to 40 MHz clock frequency
 - \square On-chip $\pm 1\%$ accurate oscillator
 - ☐ Programmable clock generator
 - □ One-clock-per-machine cycle architecture
 - \Box DMA
 - □ 16-level interrupt handler
 - □ SW-DP tw-wire debug
- · On-chip memory
 - □ up to 248 kB flash
 - \square 32 kB DRAM
 - \square 8 kB IRAM
 - □ 32 kB boot ROM

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PACKAGE



48-pin 7 mm × 7 mm QFN with exposed thermal pad and wettable flank (suffix EV)

DESCRIPTION

The A89224 is a high-performance processor with integrated three-phase gate drive and precision current sense capability. It is designed for use with advanced standalone three-phase brushless DC (BLDC) motor and permanent magnet synchronous motor (PMSM) control applications.

The processor uses the ARM cortex M4 CPU core running at 40 MHz, giving up to 50 million instructions per second (mips) performance. The processor capability is further enhanced by peripheral functions specifically designed for motor control applications. These include a pulse-width modulation (PWM) generator and sense-current capture systems capable of providing up to 12-bit control precision at up to 20 kHz PWM frequency.

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APPLICATIONS

- HVAC
- Pump

- · Cooling fan
- Seating moving

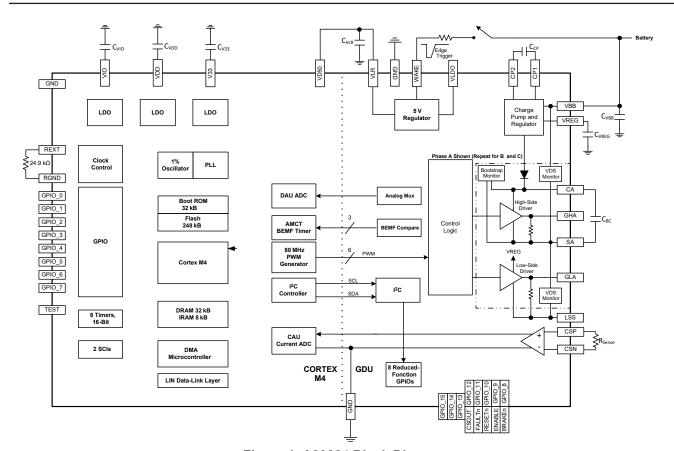


Figure 1: A89224 Block Diagram

A89224-A/B

Automotive MCU with 90 V MOSFET Driver

FEATURES AND BENEFITS (continued)

- Three-phase bridge MOSFET driver with bootstrap gate drive for N-channel MOSFET bridge
- Charge pump for low supply voltage operation
- 5 V CMOS-compatible logic I/O
- 80 MHz PWM generator
 - □ 12-bit PWM at 20 kHz
 - □ Programmable back electromagnetic force (bemf) and current-sample control
- Programmable high-performance current-sense amplifier
 3 × 11 bit, 1 μs analog-to-digital converter (ADC) for current measurement
- 12-bit 1 μs data acquisition ADC with 16-channel multiplexer (mux)
- 8 general-purpose I/O (GPIO) ports
- 8 general-purpose timers
- 2 serial communication interfaces (SCIs)
- Local-interconnect network (LIN) datalink layer
- 1-phase bemf detector
- Integrated power management
- · VDS, UVLO, and thermal shutdown diagnostic
- · Latched TSD with fault output
- Automotive AEC-Q100 Grade 1 qualified

DESCRIPTION (continued)

16 general-purpose input and output (I/O) ports provide access to programmable serial communication interfaces and analog and digital inputs and outputs.

The gate driver is an N-channel power MOSFET driver capable of controlling MOSFETs connected in a three-phase bridge arrangement and is specifically designed for power applications with high-power inductive loads, such as BLDC motors.

A unique charge-pump regulator provides the supply for the MOSFET gate drive for battery voltages as low as 7 V and allows the A89224 to operate with a reduced gate drive voltage as low as 5.5 V. A bootstrap capacitor is used to provide the greater-than-battery supply voltage required for the N-channel MOSFETs.

The power supply unit provides and manages all internal supplies from a single 5.5 to 90 V supply. The microcontroller unit (MCU) section can also operate with an independent single 5 V supply.

Integrated programmable diagnostics provide indication of multiple internal faults, system faults, and power-bridge faults, and can be configured to protect the power MOSFETs under most short-circuit conditions.

The A89224 is supplied in a 48-lead quad-flat no-lead (QFN) package with exposed thermal pad. This package is lead (Pb) free with 100% matter tin leadframe plating.

SELECTION GUIDE

| Part Number | Flash Memory (kB) | GPIO Voltage (V) | Package | |
|---------------|----------------------|---------------------|---------------------------------------------------------------------------------------------------|--|
| A89224KEVSR-A | 248 | 5 | 7 mm × 7 mm, 0.9 mm nominal height 48-terminal QFN with exposed thermal pad and wettable flank | |
| A89224KEVSR-B | 128 | 5 | 7 mm × 7 mm, 0.9 mm nominal height 48-terminal QFN with exposed thermal pad and wettable flank | |





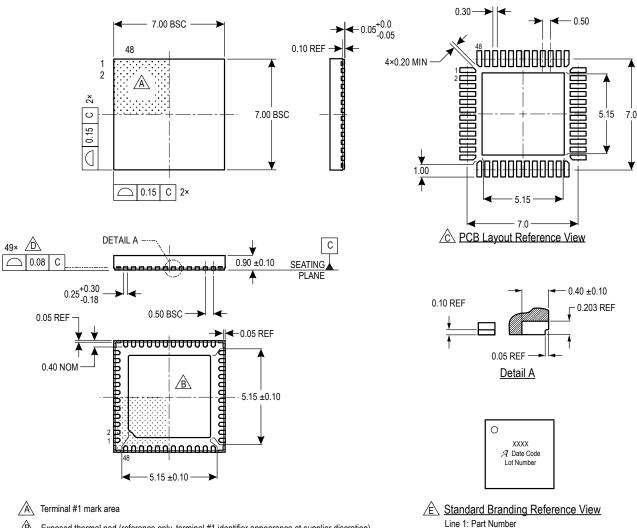
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PACKAGE OUTLINE DRAWING

For Reference Only – Not for Tooling Use (Reference DWG-0000378, Rev. 3)

Dimensions in millimeters NOT TO SCALE

Exact case and lead configuration at supplier discretion within limits shown



B Exposed thermal pad (reference only, terminal #1 identifier appearance at supplier discretion)

Reference land pattern layout (reference IPC7351 QFN50P700X700X100-49M); all pads a minimum of 0.20 mm from all adjacent pads; adjust as necessary to meet application process requirements and PCB layout tolerances; when mounting on a multilayer PCB, thermal vias at the exposed thermal pad land can improve thermal dissipation (reference EIA/JEDEC Standard JESD51-5)

Coplanarity includes exposed thermal pad and terminals

E Branding scale and appearance at supplier discretion

Line 2: Logo A, 4-digit Date Code

Line 3: Characters 5, 6, 7, 8 of Assembly Lot Number





A89224-A/B

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Revision History

| Number | Date | Description | |
|--------|-------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--|
| _ | February 18, 2025 | Initial release | |
| 1 | March 25, 2025 | Updated block diagram (page 1); updated Terminal CP value (page 4); updated VREG Output Voltage value and VLR Output Overcurrent Limit, Core Voltage, Analog Voltage, Program Cycle, and Data Retention test conditions (page 7); updated Gate Drive Pull-Up Resistance (150°C) maximum value (page 11); updated VLR Undervoltage minimum value (page 12); updated Boot ROM section (page 14); and minor editorial updates | |
| 2 | July 18, 2025 | Updated part family (all pages), block diagram (page 1); added footnote (page 7), GDU and MDU Temperature Reading Accuracy characteristics (page 11), Wake Input Threshold minimum value (page 12), and Input/Output ESD Diagram (page 28) | |

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